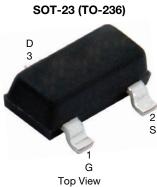
SQ2398ES

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Vishay Siliconix

Automotive N-Channel 100 V (D-S) 175 °C MOSFET



Marking Code: 9E

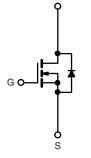
PRODUCT SUMMARY				
V _{DS} (V)	100			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.300			
I _D (A)	1.67			
Configuration	Single			

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified ^c
- 100 % $R_{\rm q}$ and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



KONS COMPLIANT HALOGEN



П

N-Channel MOSFET

ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2398ES (for detailed order number please see www.vishav.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \degree C$, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	100	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C	1	1.6		
	T _C = 125 °C	I _D	0.9		
Continuous source current (diode conduction	n)	ا _S	2.5	А	
Pulsed drain current ^a		I _{DM}	6.6		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	5		
Single pulse avalanche energy		E _{AS}	1.2	mJ	
Maximum power dissipation ^a	T _C = 25 °C	PD	2	W	
	T _C = 125 °C		0.6	vv	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount ^b	R _{thJA}	130	°C/W	
Junction-to-foot (drain)		R _{thJF}	75	0/ 11	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. When mounted on 1" square PCB (FR4 material)

c. Parametric verification ongoing

S21-1074-Rev. B, 15-Nov-2021

1

Document Number: 67117

For technical questions, contact: automos.techsupport@vishay.com

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static	•	•						
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		100	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$		3.0	3.5	v	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	-	1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA	
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	150	1	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	5	-	-	Α	
		$V_{GS} = 10 V$	I _D = 1.5 A	-	0.240	0.300	Ω	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 1.5 A, T _J = 125 °C	-	-	0.552		
		$V_{GS} = 10 V$	I _D = 1.5 A, T _J = 175 °C	-	-	0.720		
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 1.5 A	-	3	-	S	
Dynamic ^b	•				•		•	
Input capacitance	C _{iss}			-	152	-		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{GS} = 0 V V _{DS} = 50 V, f = 1 MHz		28	-	рF	
Reverse transfer capacitance	C _{rss}			-	12	-	1	
Total gate charge ^c	Qg			-	2.3	3.4		
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$	-	0.7	-	nC	
Gate-drain charge ^c	Q _{gd}			-	1.1	-		
Gate Resistance	Rg	f = 1 MHz		2.9	5.8	8.7	Ω	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 50 \text{ V}, \text{ R}_{\text{L}} = 33 \Omega$ $\text{I}_{\text{D}} \cong 1.5 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	5	6.9		
Rise Time ^c	t _r			-	18	24	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	7	9		
Fall Time ^c	t _f			-	17	23		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	8	Α	
Forward Voltage	V _{SD}	I _F = 1.5 A, V _{GS} = 0 V		-	0.8	1.2	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

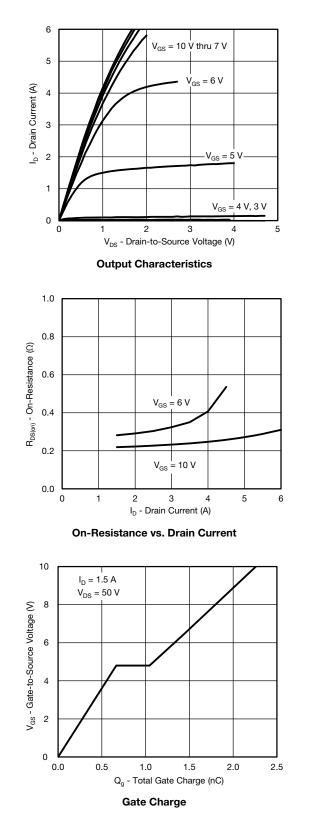
c. Independent of operating temperature

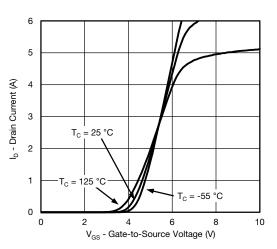
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2

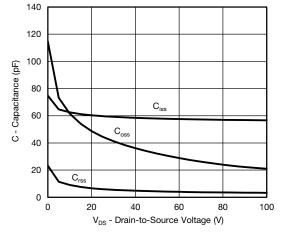


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

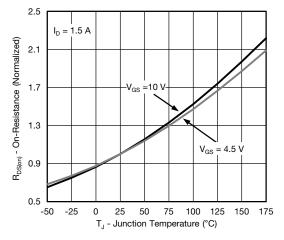




Transfer Characteristics



Capacitance



On-Resistance vs. Junction Temperature

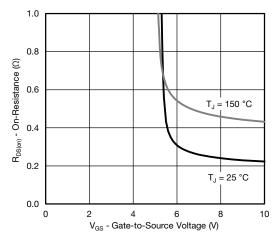
S21-1074-Rev. B, 15-Nov-2021

3

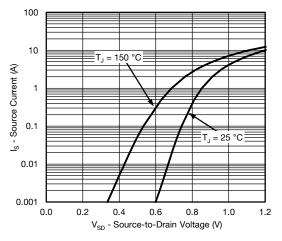
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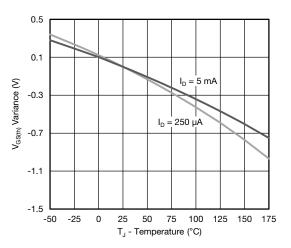
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



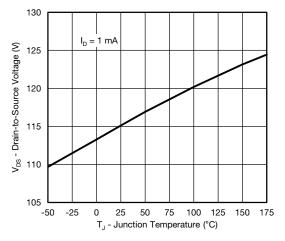
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



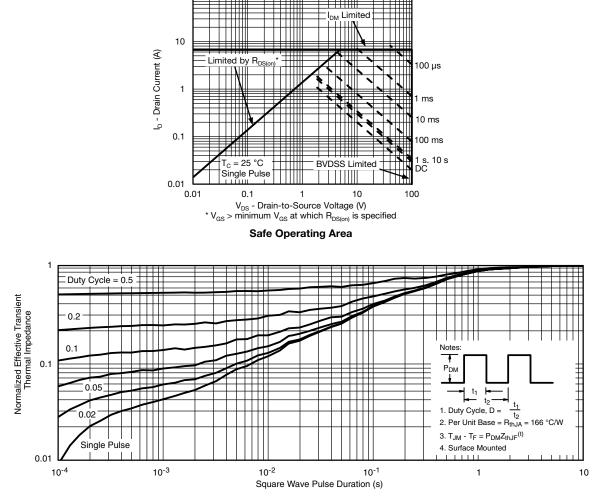
Drain Source Breakdown vs. Junction Temperature

4



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

100



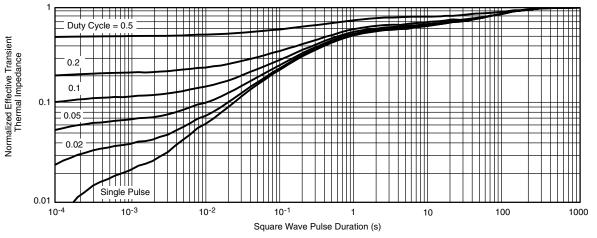
Normalized Thermal Transient Impedance, Junction-to-Ambient



SQ2398ES

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?67117.

6

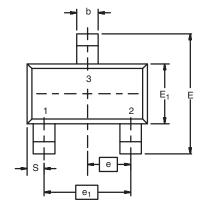
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Package Information

Vishay Siliconix

SOT-23 (TO-236): 3-LEAD







Dim	MILLIM	IETERS	INCHES		
	Min	Мах	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K, 09- DWG: 5479	Jul-01				



Application Note 826

Vishay Siliconix

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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